Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC6042

High-Speed, High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- High-speed switching: $t_f = 0.2 \mu s \text{ (max) (IC} = 0.3 \text{A)}$
- High breakdown voltage: $V_{CES} = 800 \text{ V}$, $V_{CEO} = 375 \text{ V}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	800	V	
Collector-emitter voltage		V _{CES}	800	V	
		V_{CEO}	375	V	
Emitter-base voltage		V_{EBO}	8	V	
Collector current	DC	Ic	1.0	Α	
	Pulse	I _{CP}	2.0		
Base current		ΙΒ	0.5	Α	
Collector power dissipation	Ta = 25°C	Ta = 25°C P _C 1.0		W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Weight: 0.2 g (typ.)

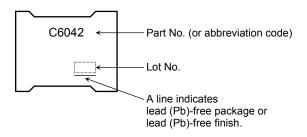
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

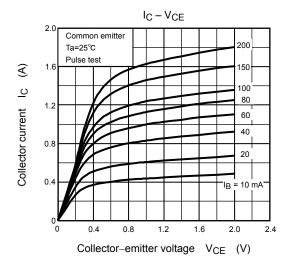
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

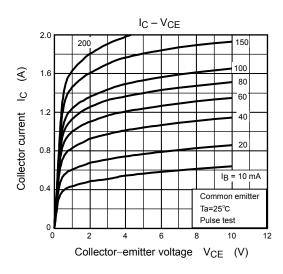
Electrical Characteristics (Ta = 25°C)

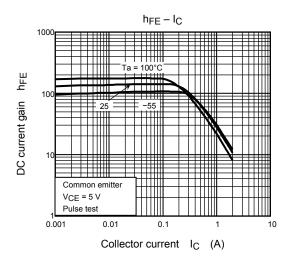
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 800 V, I _E = 0	_	_	100	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	-	_	100	μΑ
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _B = 0	800	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	375	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA	80	_	_	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.1 A	100	_	200	
		h _{FE (3)}	V _{CE} = 5 V, I _C = 0.2 A	80	_	_	
Collector emitter saturation voltage		V _{CE} (sat)	I _C = 0.8 A, I _B = 0.1 A	-	_	1.0	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 0.8 A, I _B = 0.1 A	-	_	1.3	V
Switching time	Rise time	t _r	20 μs V _{CC} ≈ 200 V B2	_	_	0.5	
	Storage time	t _{stg}		ı	_	4.5	μs
	Fall time	t _f	I _{B1} = 20 mA, −I _{B2} = 50 mA DUTY CYCLE ≤ 1%	_	_	0.2	

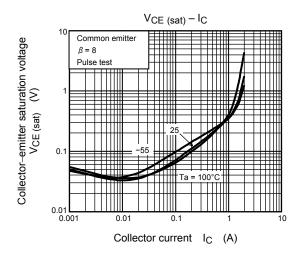
Marking

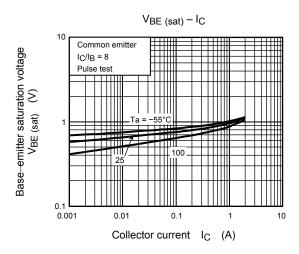


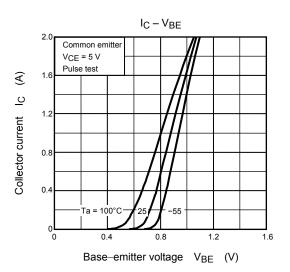


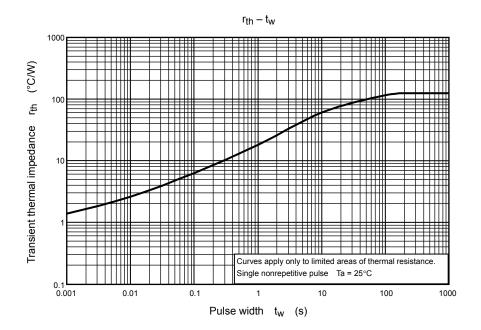


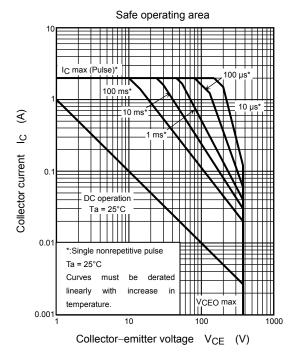


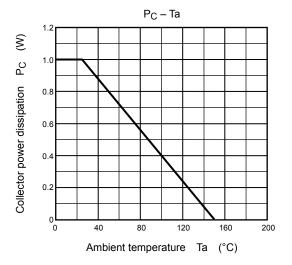












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